# 2SC4212

### Silicon NPN triple diffusion planar type

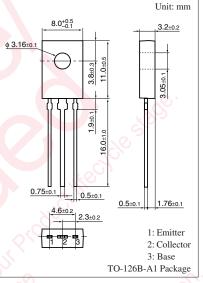
For color TV horizontal deflection driver

#### Features

- High collector-emitter voltage (Base open) V<sub>CEO</sub>
- TO-126B package which requires no insulation plate for installation to the heat sink

tion to the heat sink			
Absolute Maximum Rating	$T_a = 2$	5°C	
Parameter	Symbol	Rating	Unit
Collector-base voltage (Emitter open)	V <sub>CBO</sub>	350	V
Collector-emitter voltage (Base open)	V <sub>CEO</sub>	300	V
Emitter-base voltage (Collector open)	V <sub>EBO</sub>	7.5	v
Collector current	I <sub>C</sub>	200	mA
Peak collector current	I <sub>CP</sub>	400	mA
Collector power	P <sub>C</sub>	1.2	W
dissipation		5.0 *	3
Junction temperature	Tj	150	°C
Storage temperature	T <sub>stg</sub>	-55 to +150	°C

#### Ab



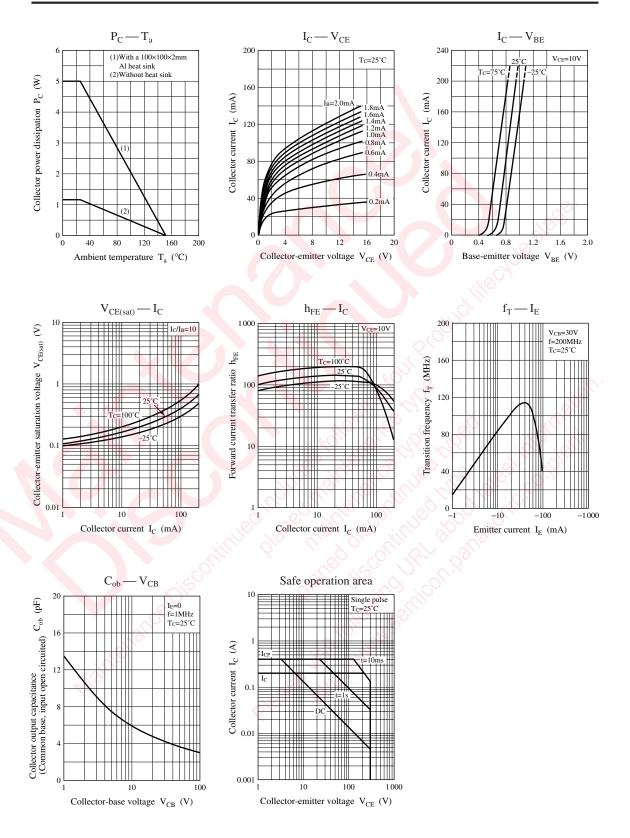
Note) \*: With a  $100 \times 100 \times 2$  mm Al heat sink

#### Electrical Characteristics $T_a = 25^{\circ}C \pm 3^{\circ}C$

Parameter	Symbol	Conditions	Min	Тур	Max	Unit
Collector-base voltage (Emitter open)	V <sub>CBO</sub>	$I_{\rm C} = 100 \ \mu A, I_{\rm E} = 0$	350			V
Collector-emitter voltage (Base open)	V <sub>CEO</sub>	$I_{\rm C} = 5 \text{ mA}, I_{\rm B} = 0$	300			V
Emitter-base voltage (Collector open)	V <sub>EBO</sub>	$I_{\rm E} = 100 \mu {\rm A},  I_{\rm C} = 0$	7.5			V
Collector-base cutoff current (Emitter open)	I <sub>CBO</sub>	$V_{CB} = 200 \text{ V}, I_E = 0$			2	μΑ
Emitter-base cutoff current (Collector open)	I <sub>EBO</sub>	$V_{EB} = 5 V, I_C = 0$			2	μΑ
Forward current transfer ratio	h <sub>FE</sub>	$V_{CE} = 10 \text{ V}, I_{C} = 10 \text{ mA}$	40		250	—
Collector-emitter saturation voltage	V <sub>CE(sat)</sub>	$I_{\rm C} = 50 \text{ mA}, I_{\rm B} = 5 \text{ mA}$			1	V
Transition frequency	f <sub>T</sub>	$V_{CB} = 30 \text{ V}, I_E = -10 \text{ mA}, f = 200 \text{ MHz}$	50	80		MHz
Collector output capacitance	C <sub>ob</sub>	$V_{CB} = 50 \text{ V}, I_E = 0, f = 1 \text{ MHz}$			4.5	pF
(Common base, input open circuited)		•				

Note) Measuring methods are based on JAPANESE INDUSTRIAL STANDARD JIS C 7030 measuring methods for transistors.

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